Low Noise, Wideband, High IP3

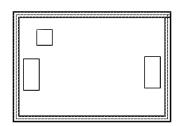
Monolithic Amplifier Die

PMA3-83LN-D+

50Ω 0.5 to 8.0 GHz

The Big Deal

- · Flat gain over wideband
- Low noise figure, 1.2 dB
- High IP3, up to +37 dBm



Product Overview

The PMA3-83LN-D+ is a PHEMT based wideband, low noise MMIC amplifier die with a unique combination of low noise, high IP3, and flat gain over wideband making it ideal for sensitive, high-dynamic-range receiver applications. This design operates on a single 5V or 6V supply and is well matched to 50 \supset .

Key Features

Feature	Advantages		
Low noise, 1.2 dB at 2 GHz	Enables lower system noise figure performance.		
High IP3 • +36.8 dBm at 2 GHz and 6V • +29.9 dBm at 8 GHz and 6V	Combination of low noise and high IP3 makes this MMIC amplifier ideal for use in I noise receiver front end (RFE) as it gives the user advantages of sensitivity and tw tone IM performance at both ends of the dynamic range.		
Low operating voltage, 5V/6V.	Achieves high IP3 using low voltage.		
Wide bandwidth with flat gain • ±0.9 dB over 0.5 to 7 GHz • ±1.2 dB over 0.5 to 8 GHz	Enables a single amplifier to be used in many wideband applications including de instrumentation and more.		
Unpackaged Die	Enables users to integrate amplifiers directly into hybrids		

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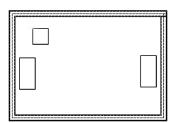
 50Ω 0.5 to 8.0 GHz

Product Features

- Low Noise figure, 1.2 dB at 2 GHz
- High IP3, 35 dBm typ. at 2 GHz
- High Pout, P1dB 20.7 dBm typ. at 2 GHz and 6V
- Excellent Gain flatness, ±0.9 dB over 0.5 to 7 GHz and 6V

Typical Applications

- WiFi
- WLAN
- UMTS
- LTE
- WiMAX
- S-band Radar
- C-band Satcom



+RoHS Compliant

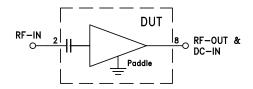
The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

Ordering Information: Refer to Last Page

General Description

The PMA3-83LN-D+ is a PHEMT based wideband, low noise MMIC amplifier die with a unique combination of low noise, high IP3, and flat gain over wideband making it ideal for sensitive, high-dynamic-range receiver applications. This design operates on a single 5V or 6V supply and is well matched to 50⊃.

Simplified Schematic and Pad description



Function	Description (See Figure 1)	
RF-IN	Connects to RF input and to ground via L1 (optional blocking capacitor of 100pF may be used)	
RF-OUT & DC-IN	Connects to RF out via C3 and V _{DD} via L2	
Ground	Bottom of die	

Note: 1. Bond Pad material - Gold 2. Bottom of Die - Gold plated



Electrical Specifications¹ at 25°C and 5V, unless noted

Parameter	Condition		V _{DD} =6.0		V _{DD} =5.0	Units
	(GHz)	Min.	Тур.	Max.	Тур.	
Frequency range		0.5		8.0	0.5-8.0	GHz
Noise figure	0.5		1.8		1.8	dB
	2.0		1.2		1.2	
	4.0		1.3		1.4	
	8.0		1.6		1.7	
Gain	0.5		21.7		20.8	dB
	2.0		21.9		21.1	
	4.0		21.4		20.6	
	8.0		19.8		19.3	
Input return loss	0.5		14.5		13.3	dB
	2.0		15.6		16.4	
	4.0		12.7		11.8	
	8.0		8.1		7.8	
Output return loss	0.5		12.4		13.5	dB
	2.0		10.8		12.0	
	4.0		20.9		23.9	
	8.0		11.0		10.7	
Output power at 1dB compression ²	0.5		18.6		16.1	dBm
	2.0		21.2		19.6	
	4.0		19.0		16.9	
	8.0		17.7		16.7	
Output IP3	0.5		34.7		29.6	dBm
	2.0		36.8		30.5	
	4.0		32.5		27.8	
	8.0		29.9		26.7	
Device operating voltage (V _{DD})		_	6.0	_	5.0	V
Device operating current (I _{DD})		_	77	94	60	mA
Device current variation vs. voltage			0.016		0.019	mA/mV
Thermal resistance, junction-to-ground lead			40		40	°C/W

^{1.} Measured on Mini-Circuits Characterization test board. See Characterization Test Circuit (Fig. 1) 2. Current increases at P1dB to 109 mA typ. at +6V V_{DD} and 88mA typ. at +5V V_{DD}

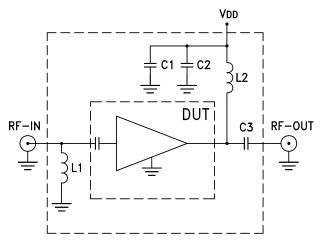
Absolute Maximum Ratings^{3,4}

Parameter	Ratings	
Operating Temperature	-40°C to 85°C	
Junction Temperature	150°C	
Total Power Dissipation	0.95 W	
Input Power (CW), Vd=5,6V	+19 dBm (5 minutes max.) +16 dBm (continuous)	
DC Voltage	7 V	

 ^{3.}Permanent damage may occur if any of these limits are exceeded.
 Electrical maximum ratings are not intended for continuous normal operation.
 4. Die performance measured in industry standard 3x3 mm 12-lead MCLP package.



Recommended Application and Characterization Test Circuit



Component	Value	Size
C1	0.01µF	0402
C2	10pF	0402
C3	100pF	0402
L1	18nH	0402
L2	39nH	0402

Fig 1. Application and Characterization circuit

Gain, Return loss, Output power at 1dB compression (P1 dB), output IP3 (OIP3) and noise figure measured using Keysight's N5242A PNA-X microwave network analyzer.

Conditions:

- 1. Gain and Return loss: Pin= -25dBm
- 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 0 dBm/tone at output.

Die Layout

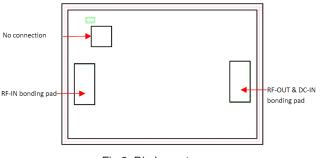
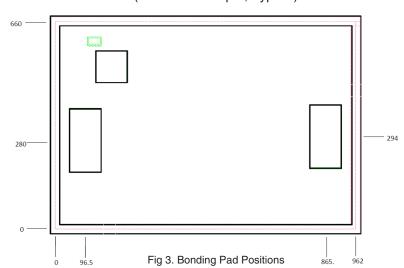


Fig 2. Die Layout

Bonding Pad Position

(Dimensions in µm, Typical)



Critical Dimensions

Parameter	Values
Die Thickness, µm	100
Die Width, µm	660
Die Length, μm	962
Bond Pad Size, µm	100 X 200

Assembly and Handling Procedure

1. Storage

Dice should be stored in a dry nitrogen purged desiccators or equivalent.

2. ESD

MMIC Gallium Arsenide (GaAs) amplifier dice are susceptible to electrostatic and mechanical damage. Die are supplied in antistatic protected material, which should be opened in clean room conditions at an appropriately grounded anti-static worksta tion. Devices need careful handling using correctly designed collets, vacuum pickup tips or sharp antistatic tweezers to deter ESD damage to dice.

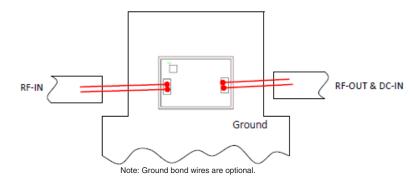
3. Die Attach

The die mounting surface must be clean and flat. Using conductive silver filled epoxy, recommended epoxies are DieMat DM6030HK-PT/H579 or Ablestik 84-1LMISR4. Apply sufficient epoxy to meet required epoxy bond line thickness, epoxy fillet height and epoxy coverage around total die periphery. Parts shall be cured in a nitrogen filled atmosphere per manufacturer's cure condition. It is recommended to use antistatic die pick up tools only.

4. Wire Bonding

Bond pad openings in the surface passivation above the bond pads are provided to allow wire bonding to the dice gold bond pads. Thermosonic bonding is used with minimized ultrasonic content. Bond force, time, ultrasonic power and temperature are all critical parameters. Suggested wire is pure gold, 1 mil diameter. Bonds must be made from the bond pads on the die to the package or substrate. All bond wires should be kept as short as low as reasonable to minimize performance degradation due to undesirable series inductance.

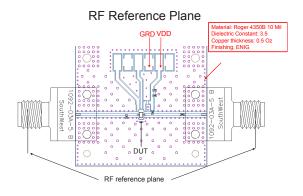
Assembly Diagram



Recommended Wire Length, Typical

Wire	Wire Length (mm)	Wire Loop Height (mm)
RF-IN	0.5	0.15
RF-OUT & DC IN	0.5	0.15

RF Reference Plane - No port extension



Data Table		
Swept Graphs		
S-Parameter (S2P Files) Data Set with and without port extension(.zip file)		
Die		
Quantity, Package	Model No.	
Small, Gel - Pak: 5,10,50,100 KGD* Medium [†] , Partial wafer: KGD*<1910 Large [†] , Full Wafer		
†Available upon request contact sales representative		
	Swept Graphs S-Parameter (S2P Files) Data Set with Die Quantity, Package Small, Gel - Pak: 5,10,50,100 KGD* Medium [†] , Partial wafer: KGD*<1910 Large [†] , Full Wafer	

^{*}Known Good Dice ("KGD") means that the dice in question have been subjected to Mini-Circuits DC test performance criteria and measurement instructions and that the parametric data of such dice fall within a predefined range. While DC testing is not definitive, it does help to provide a higher degree of confidence that dice are capable of meeting typical RF electrical parameters specified by Mini-Circuits.

ESD Rating**

Human Body Model (HBM): Class 1A (250 to <500V) in accordance with ANSI/ESD STM 5.1 - 2001

Additional Notes

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
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^{**} Tested in industry standard 12-lead, 3x3 mm MCLP package.